

2SA2166

FOR GENERAL PURPOSE HIGH CURRENT DRIVE APPLICATION
SILICON PNP EPITAXIAL TYPE

DESCRIPTION

ISAHAYA 2SA2166 is a silicon PNP epitaxial type transistor designed with high collector current, low $V_{CE(sat)}$.

FEATURE

- High collector current

$$I_{C(MAX)} = -500\text{mA}$$

- Low collector to emitter saturation voltage

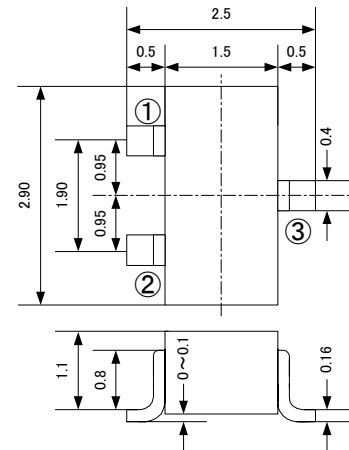
$$V_{CE(sat)} < -0.4V_{max} (I_C = -150\text{mA}, I_B = -15\text{mA})$$

APPLICATION

For switching application, small type motor drive application.

OUTLINE DRAWING

Unit: mm



Notice: The dimension without tolerance represent central value.

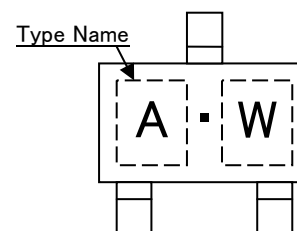
TERMINAL CONNECTOR

- ①: BASE EIAJ: SC-59
- ②: EMITTER JEDEC: TO-236
- ③: COLLECTOR Resemblance

MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

記号	項目	定格値	単位
V_{CEO}	Collector to Emitter voltage	-60	V
V_{CBO}	Collector to Base voltage	-60	V
V_{EBO}	Emitter to Base voltage	-5	V
I_C	Collector current	-500	mA
P_C	Collector dissipation	200	mW
T_j	Junction temperature	150	$^\circ\text{C}$
T_{stg}	Storage temperature	-55 ~ 150	$^\circ\text{C}$

MARKING

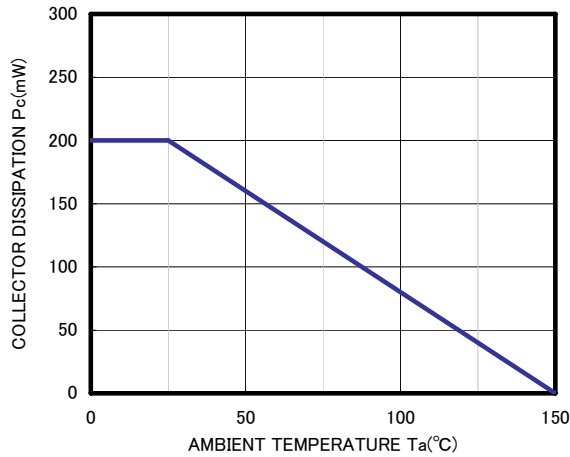


ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)

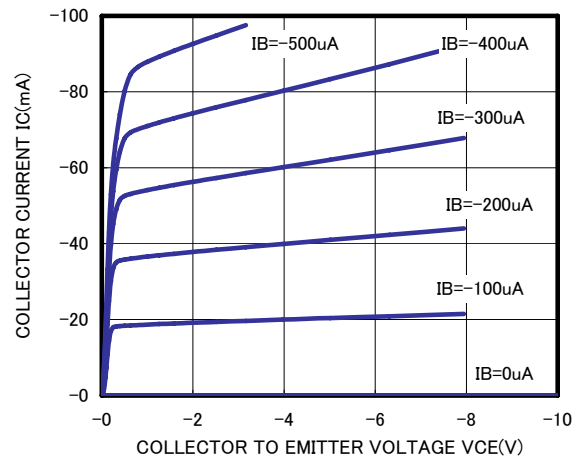
Symbol	Parameter	Test condition	Limits			Unit
			Min	Typ	Max	
$V_{(BR)CEO}$	C to E break down voltage	$I_C = -1\text{mA}, I_B = 0$	-60			V
$V_{(BR)CBO}$	C to B break down voltage	$I_C = -10\mu\text{A}, I_E = 0$	-60			V
$V_{(BR)EBO}$	E to B break down voltage	$I_E = -10\mu\text{A}, I_C = 0$	-5			V
I_{CBO}	Collector cut off current	$V_{CB} = -50\text{V}, I_E = 0$			-100	nA
I_{EBO}	Emitter cut off current	$V_{EB} = -3\text{V}, I_C = 0$			-100	nA
h_{FE}	DC forward current gain	$I_C = -150\text{mA}, V_{CE} = -10\text{V}$	100		300	---
$V_{CE(sat)}$	C to E saturation voltage	$I_C = -150\text{mA}, I_B = -15\text{mA}$			-0.4	V
$V_{BE(sat)}$	B to E saturation voltage	$I_C = -150\text{mA}, I_B = -15\text{mA}$			-1.3	V
f_T	Gain band width product	$I_E = 50\text{mA}, V_{CE} = -20\text{V}, f = 100\text{MHz}$	200			MHz
C_{ob}	Collector output capacitance	$V_{CB} = -10\text{V}, f = 1\text{MHz}$			8	pF

TYPICAL CHARACTERISTICS

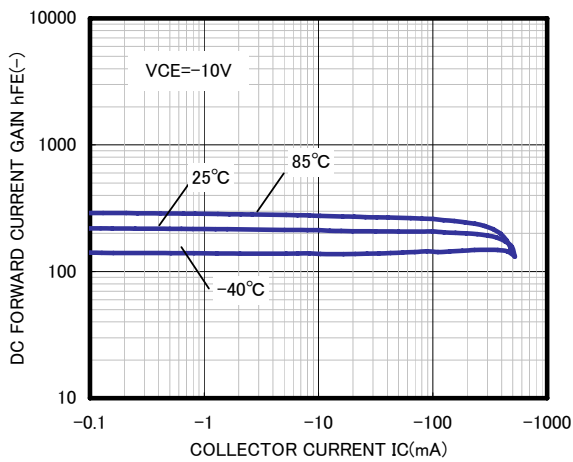
COLLECTOR DISSIPATION VS. AMBIENT TEMPERATURE



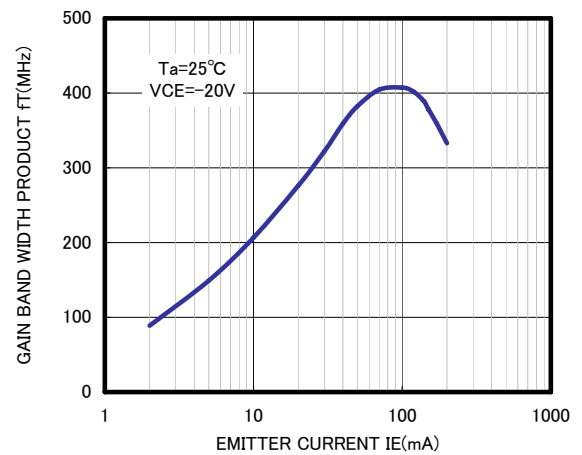
COMMON EMITTER OUTPUT $T_a=25^\circ\text{C}$



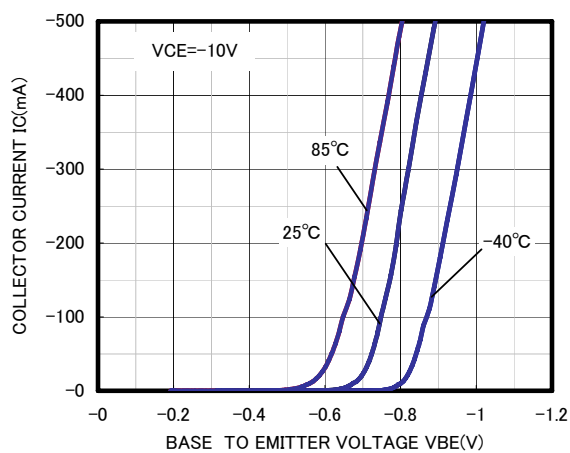
DC FORWARD CURRENT GAIN VS. COLLECTOR CURRENT



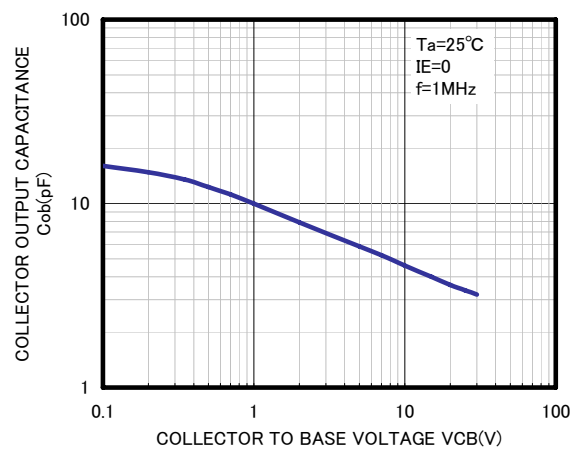
GAIN BAND WIDTH PRODUCT VS. EMITTER CURRENT



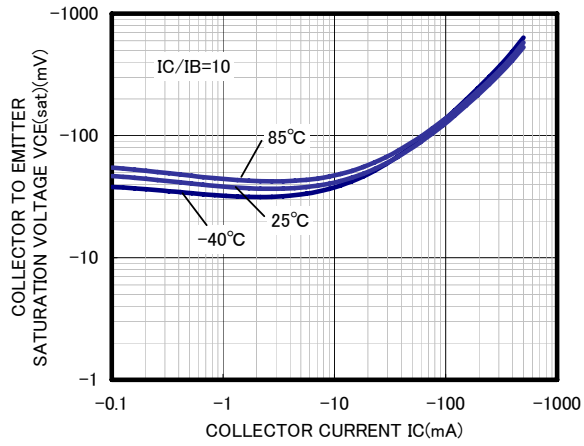
COMMON EMITTER TRANSFER



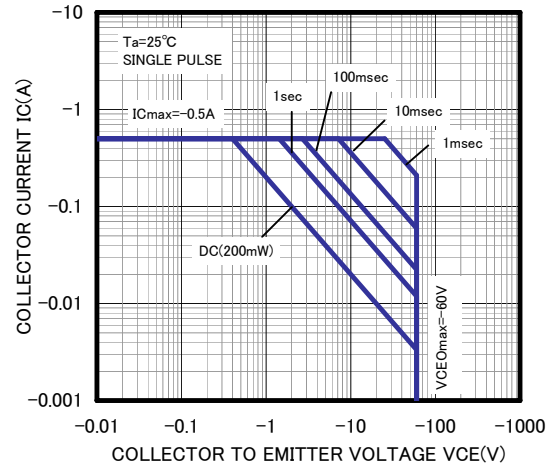
COLLECTOR OUTPUT CAPACITANCE VS. COLLECTOR TO BASE VOLTAGE



COLLECTOR TO EMITTER SATURATION VOLTAGE
VS. COLLECTOR CURRENT



AREA OF SAFE OPERATION





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